

TOSHIBA Intelligent Power Module Silicon N Channel IGBT

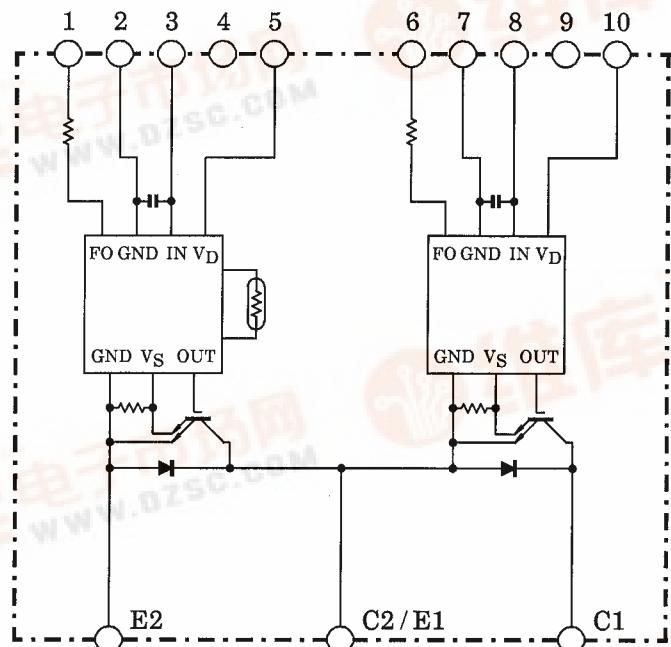
MIG300J101H

High Power Switching Applications

Motor Control Applications

- Integrates inverter power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over temperature) in one package.
- The electrodes are isolated from case.
- High speed type IGBT : $V_{CE}(\text{sat}) = 2.5\text{V}$ (max)
 $t_{off} = 2.6\mu\text{s}$ (max)
 $t_{rr} = 0.15\mu\text{s}$ (max)
- Package dimensions : TOSHIBA 2-121A1A
- Weight : 520g

Equivalent Circuit



1. FO (L) 2. GND (L) 3. IN (L) 4. Open 5. VD (L)
 6. FO (H) 7. GND (H) 8. IN (H) 9. Open 10. VD (H)

Maximum Ratings ($T_j = 25^\circ\text{C}$)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V_{CC}	450	V
	Collector-emitter voltage	—	V_{CES}	600	V
	Collector current	$T_c = 25^\circ\text{C}$, DC	I_C	300	A
	Forward current	$T_c = 25^\circ\text{C}$, DC	I_F	300	A
	Collector power dissipation	$T_c = 25^\circ\text{C}$	P_C	1200	W
	Junction temperature	—	T_j	150	$^\circ\text{C}$
Control	Control supply voltage	V_D -GND terminal	V_D	20	V
	Input voltage	IN-GND terminal	V_{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V_{FO}	20	V
	Fault output current	FO sink current	I_{FO}	14	mA
Module	Operating temperature	—	T_C	-20~+100	$^\circ\text{C}$
	Storage temperature range	—	T_{stg}	-40~+125	$^\circ\text{C}$
	Isolation voltage	AC 1 minute,	V_{ISO}	2500	V
	Screw torque	M6	—	3	Nm

Electrical Characteristics ($T_j = 25^\circ\text{C}$)

a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Typ.	Max	Unit
Collector cut-off current	I_{CEX}	$V_{CE} = 600\text{V}$	$T_j = 25^\circ\text{C}$	—	—	2	mA
			$T_j = 125^\circ\text{C}$	—	—	40	
Collector-emitter saturation voltage	V_{CE} (sat)	$V_D = 15\text{V}$, $I_C = 300\text{A}$ $V_{IN} = 3\text{V} \rightarrow 0\text{V}$	$T_j = 25^\circ\text{C}$	—	2.0	2.5	V
			$T_j = 125^\circ\text{C}$	—	2.0	—	
Forward voltage	V_F	$I_F = 300\text{A}$	—	2.1	2.7	—	V
Switching time	t_{on}	$V_{CC} = 300\text{V}$, $I_C = 300\text{A}$ $V_D = 15\text{V}$, $V_{IN} = 3\text{V} \leftrightarrow 0\text{V}$ Inductive load	(Note 1)	1.1	1.8	2.5	μs
	t_c (on)			—	0.8	1.2	
	t_{rr}			—	0.08	0.15	
	t_{off}			—	1.9	2.6	
	t_c (off)			—	0.3	0.6	

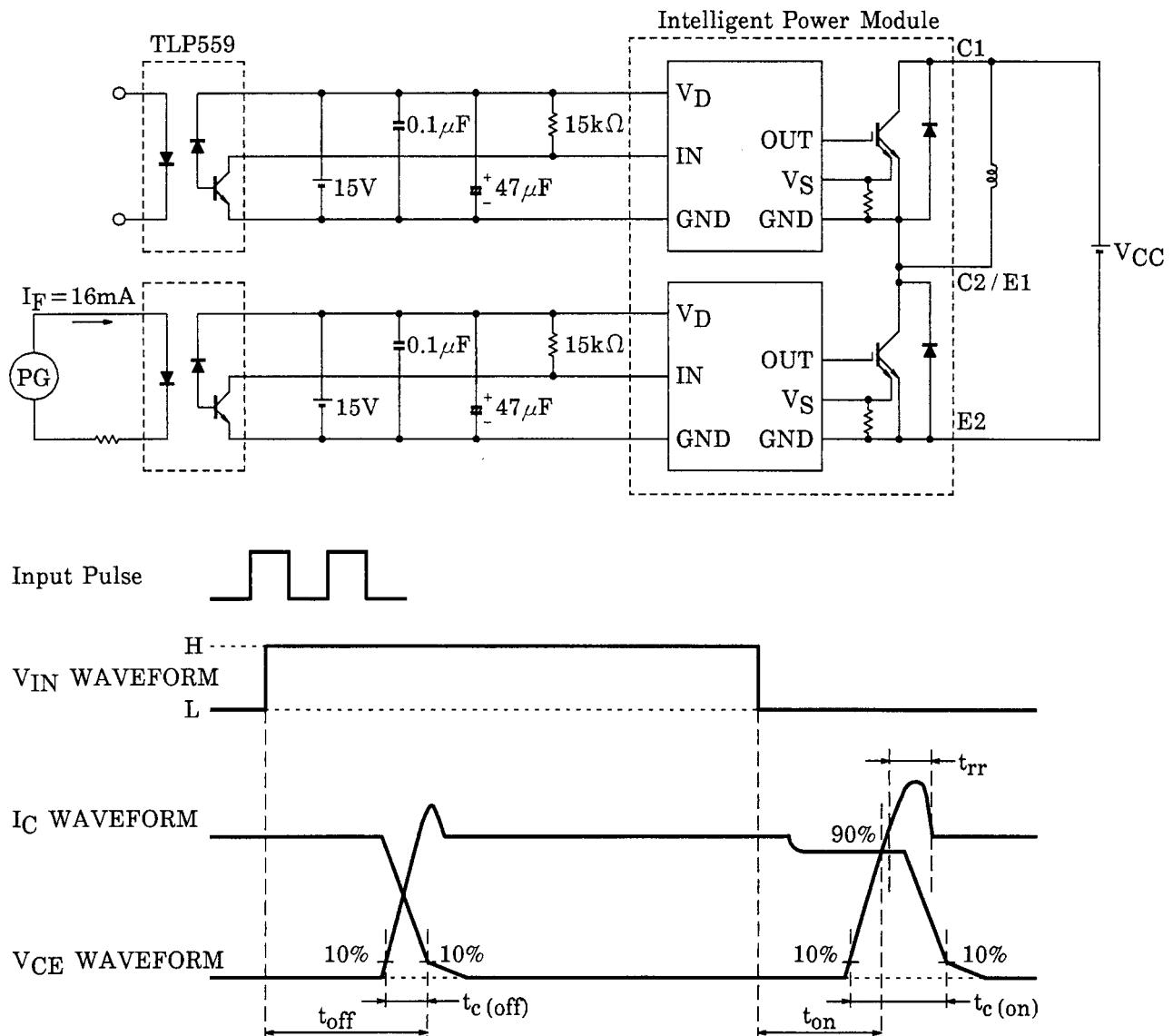
b. Control Stage

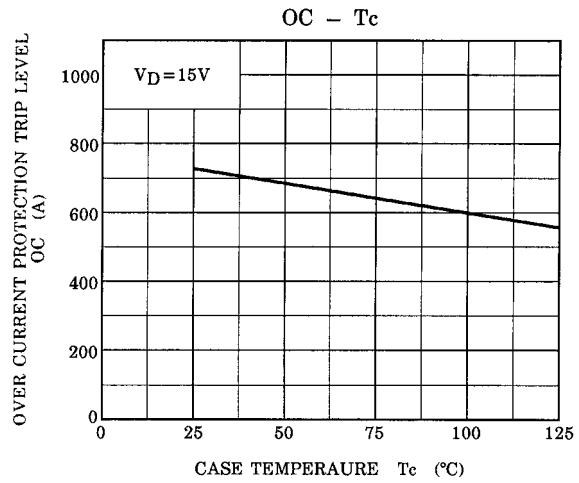
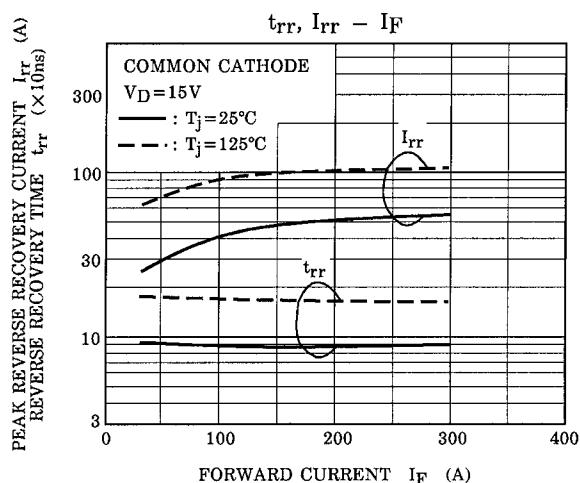
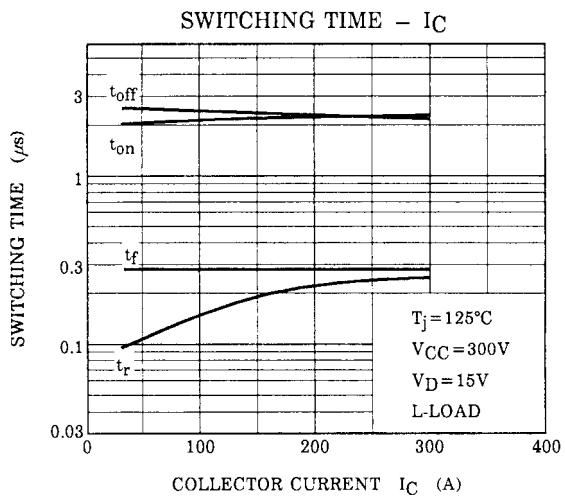
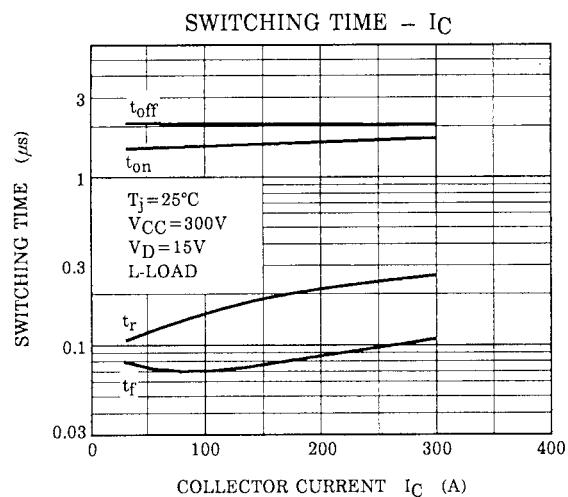
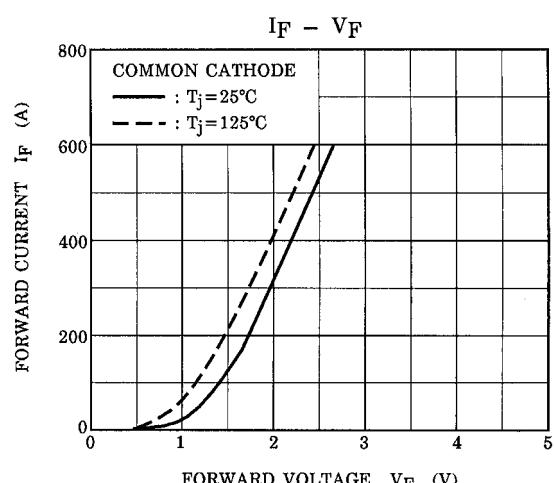
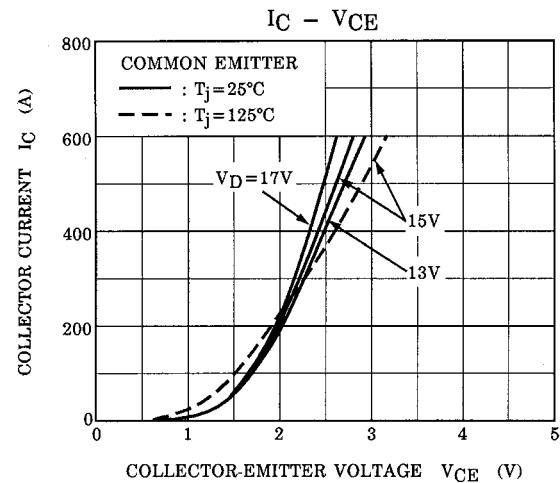
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Control circuit current		I_D	$V_D = 15V$	—	20	30	mA
Input on signal voltage		V_{IN} (on)	$V_D = 15V, I_C = 300mA$	0.9	1.1	1.3	V
Fault output current	Protection	I_{FO} (on)	$V_D = 15V$	8	10	12	mA
	Normal	I_{FO} (off)		—	—	1	
Over current protection trip level		OC	$V_D = 15V, T_j = 125^\circ C$	420	540	—	A
Short circuit protection trip level		SC	$V_D = 15V, T_j = 125^\circ C$	630	810	—	A
Over current cut-off time		t_{off} (OC)	$V_D = 15V$	—	10	—	μs
Over temperature protection	Trip level	OT	Case temperature	111	118	125	$^\circ C$
	Reset level	OTr		93	100	107	
Control supply under voltage protection	Trip level	UV	—	11.3	12.0	12.7	V
	Reset level	UVr		11.8	12.5	13.2	
Fault output pulse width		t_{FO}	$V_D = 15V$	1	2	3	ms

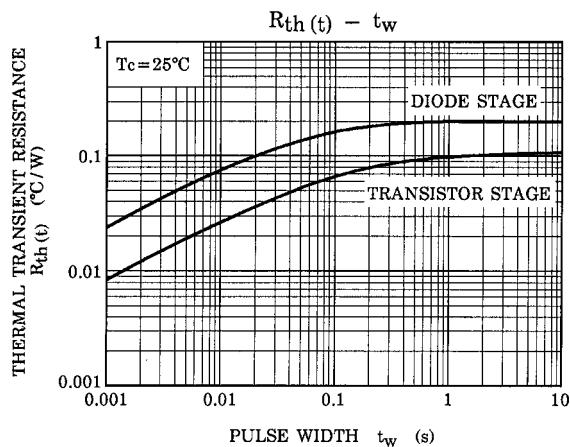
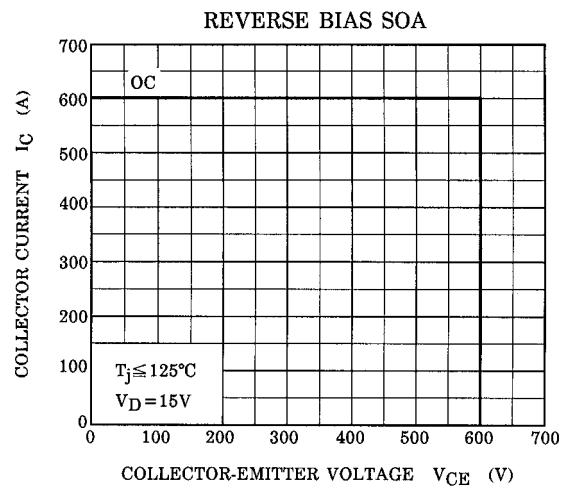
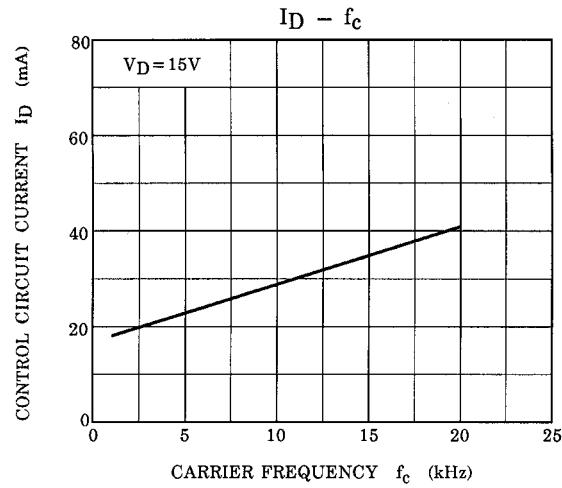
c. Thermal Resistance ($T_j = 25^\circ C$)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Junction to case thermal resistance	R_{th} (j-c)	IGBT		—	—	0.104	$^\circ C / W$
		FRD		—	—	0.208	
Case to fin thermal resistance	R_{th} (c-f)	Compound is applied		—	0.05	—	$^\circ C / W$

Note 1: Switching time test circuit & timing chart

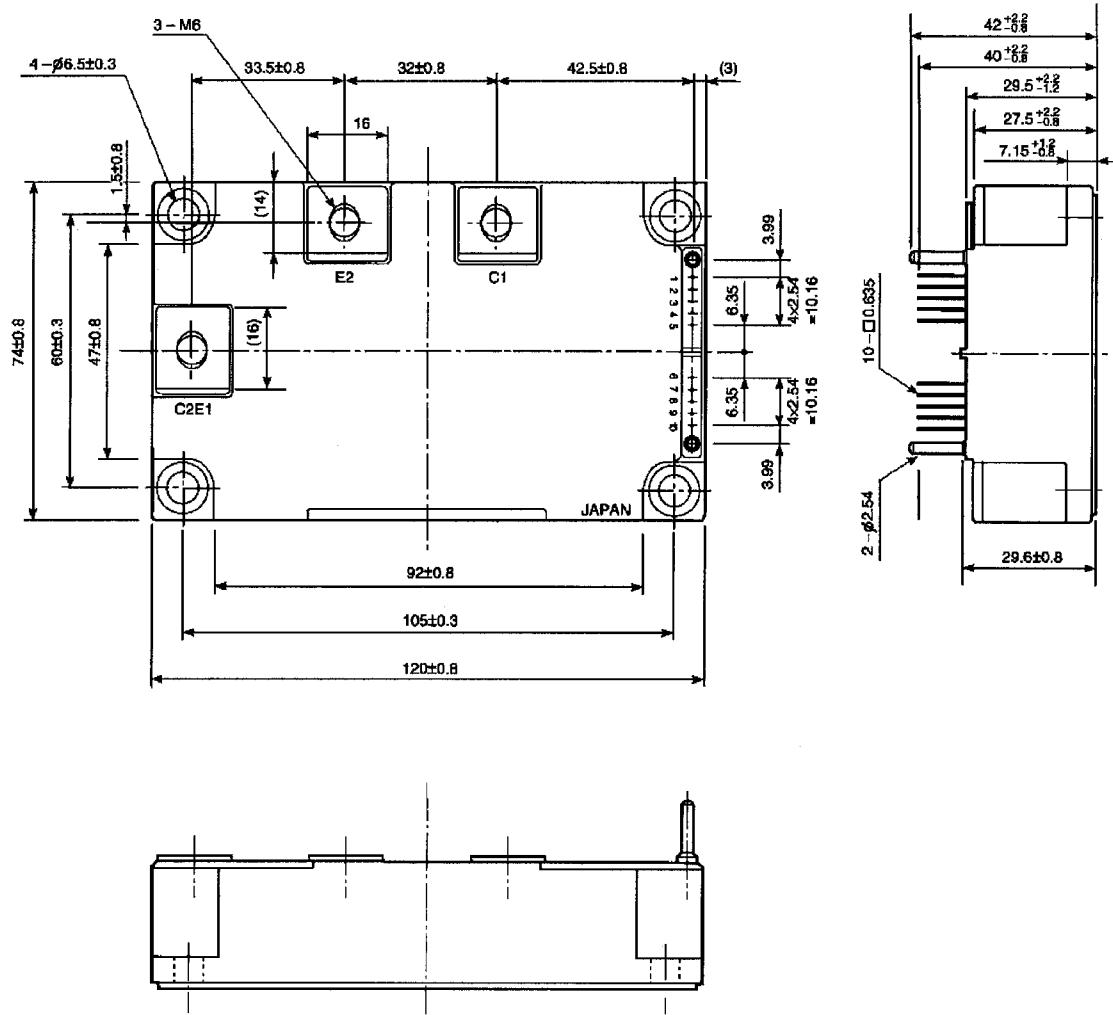






Package Dimensions: TOSHIBA 2-121A1A

Unit: mm



1. FO (L) 2. GND (L) 3. IN (L) 4. Open 5. V_D (L)
 6. FO (H) 7. GND (H) 8. IN (H) 9. Open 10. V_D (H)

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